

Features

- Advanced rectifier proprietary process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation

Description

This dual center tap field effect rectifier provides stable leakage current over the full range of reverse voltage and low forward voltage drop.

Packaged in TO-220AB or D²PAK, this device is intended to be used in solar bypass junction boxes and in switch mode power supplies.

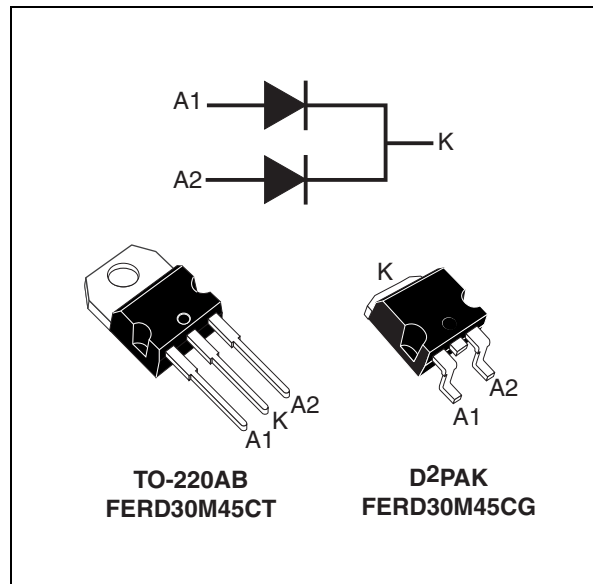


Table 1. Device summary

Symbol	Value
$I_{F(AV)}$	2 x 15 A
V_{RRM}	45 V
$T_j(max)$	+175 °C up to 200 °C forward mode
$V_F(typ)$	0.35 V

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol	Parameter		Value	Unit	
V _{RRM}	Repetitive peak reverse voltage		45	V	
I _{F(RMS)}	Forward rms current		30	A	
I _{F(AV)}	Average forward current, δ = 0.5	T _c = 155 °C	Per diode	15	A
		T _c = 155 °C	Per device	30	
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	250	A	
T _{stg}	Storage temperature range		-65 to + 175	°C	
T _j	Maximum operating junction temperature		175	°C	
T _j	Maximum operating temperature (DC forward current without reverse bias, t = 1 hour) ⁽¹⁾		200	°C	

1. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 3. Thermal resistance

Symbol	Parameter		Value (max)	Unit
R _{th(j-c)}	Junction to case	Per diode	1.6	°C/W
		Total	1.05	
R _{th(c)}	Coupling		0.5	

When diodes 1 and 2 are used simultaneously:

$$T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit	
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ }^\circ\text{C}$	$V_R = V_{RRM}$		600	μA	
		$T_j = 125\text{ }^\circ\text{C}$		25	50	mA	
$V_F^{(2)}$	Forward voltage drop	$T_j = 125\text{ }^\circ\text{C}$	$I_F = 7.5\text{ A}$		0.305	0.350	V
		$T_j = 125\text{ }^\circ\text{C}$	$I_F = 10\text{ A}$		0.350	0.395	
		$T_j = 25\text{ }^\circ\text{C}$	$I_F = 15\text{ A}$		0.420	0.470	
		$T_j = 125\text{ }^\circ\text{C}$			0.420	0.450	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$
2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.27 \times I_{F(AV)} + 0.012 I_{F(RMS)}^2$$

Figure 1. Average forward power dissipation versus average forward current (per diode)

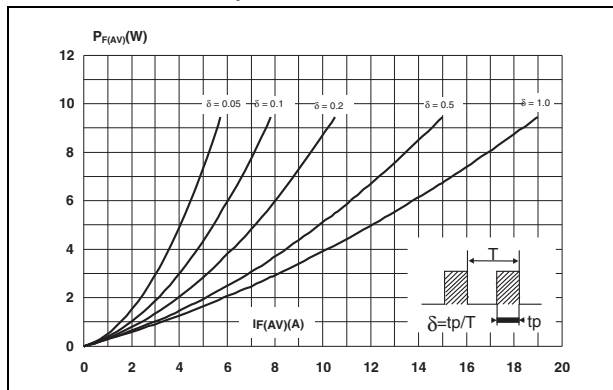


Figure 2. Average forward current versus ambient temperature (delta = 0.5, per diode)

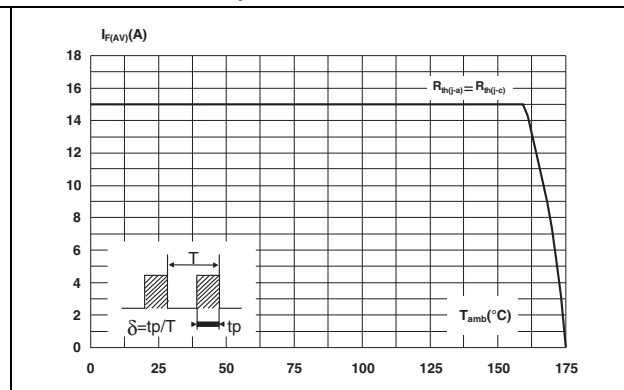


Figure 3. Junction capacitance versus reverse voltage applied (typical values, per diode)

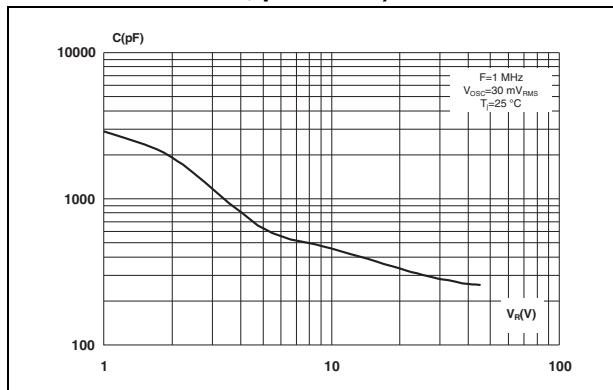


Figure 4. Forward voltage drop versus forward current (per diode)

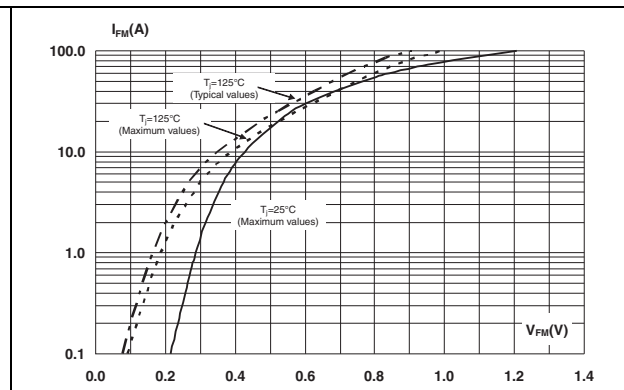


Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

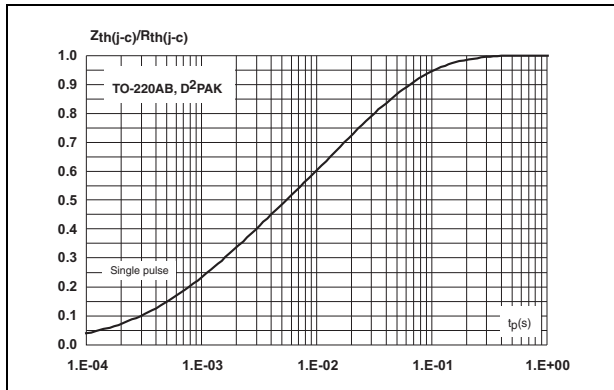
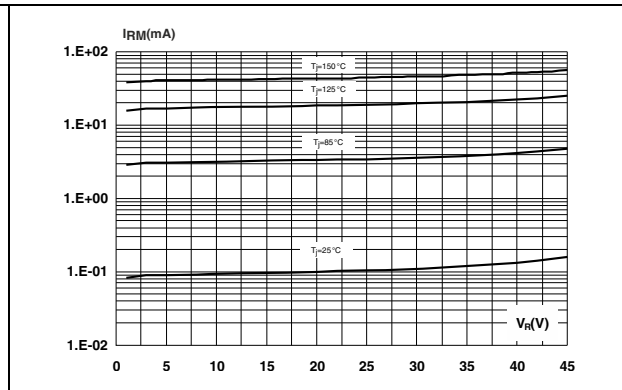


Figure 6. Reverse leakage current versus reverse voltage applied (typical values, per diode)



2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 to 1.0 N·m

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Table 5. D²PAK dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

Figure 7. Footprint (dimensions in mm)

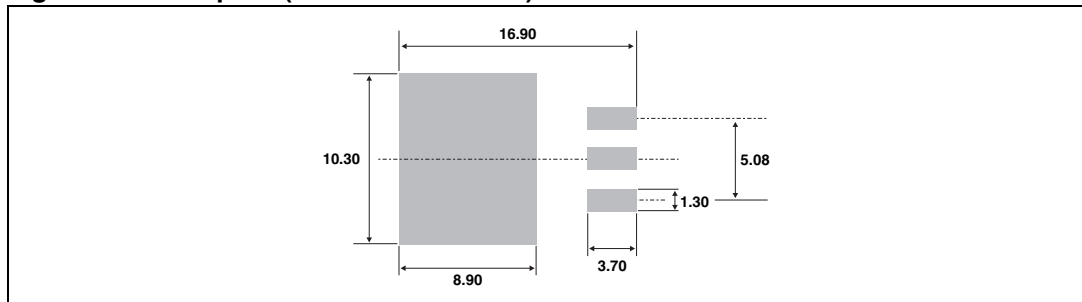
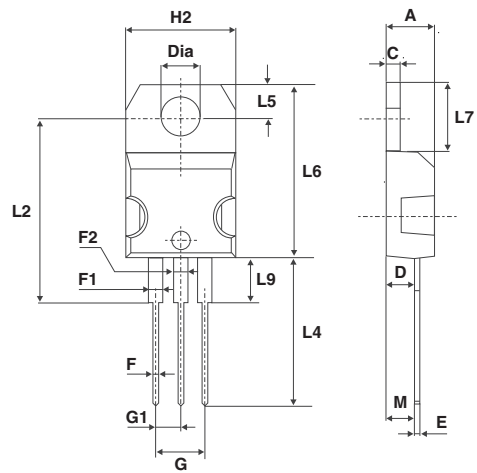


Table 6. TO-220AB dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151



3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
FERD30M45CT	FERD30M45CT	TO-220AB	2.2 g	50	Tube
FERD30M45CG-TR	FERD30M45CG	D ² PAK	1.5 g	1000	Tape and reel

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
12-Nov-2012	1	Initial release.

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